XCL241/XCL242 Series

ETR28027-001a

HiSAT-COT® Control 500mA Inductor Built-in Step-Down “micro DC/DC” Converters

☆Green Operation Compatible

■GENERAL DESCRIPTION

The XCL241/XCL242 series is a synchronous step-down micro DC/DC converter which integrates an inductor and a control IC in one tiny package (2.5mmx2.0mm, h=1.04mm). An internal coil simplifies the circuit and enables minimization of noise and other operational trouble due to the circuit wiring.

The Output voltage is internally set in a range from 0.8V to 3.6V increments of 0.05V.

HiSAT-COT is a proprietary high-speed transient response technology for DC/DC converter which was minimized output voltage during load fluctuations. It is Ideal for the applications with large instantaneous load fluctuations such as FPGAs and equipment that requires stable output voltage.

(*) HiSAT-COT is a proprietary high-speed transient response technology for DC/DC converter which was developed by Torex. It is Ideal for the LSI's that require high precision and high stability power supply voltage.

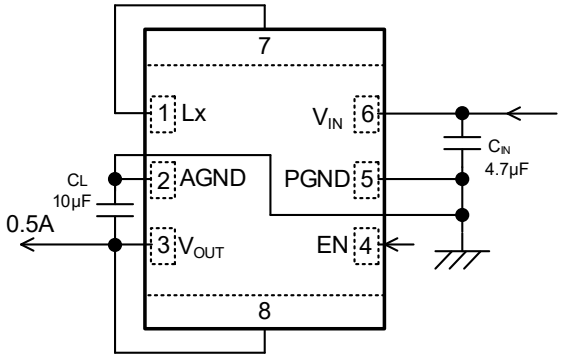
■APPLICATIONS

- Communication equipment / modules (Bluetooth/Wi-Fi/GPS etc.)
- Power supply for MCU/FPGA/ASIC (POL power supply)
- Smart phones/Mobile phones
- DSC/Camcorder
- Portable game consoles
- Wearable devices
- Active cable/Active optical cable

■FEATURES

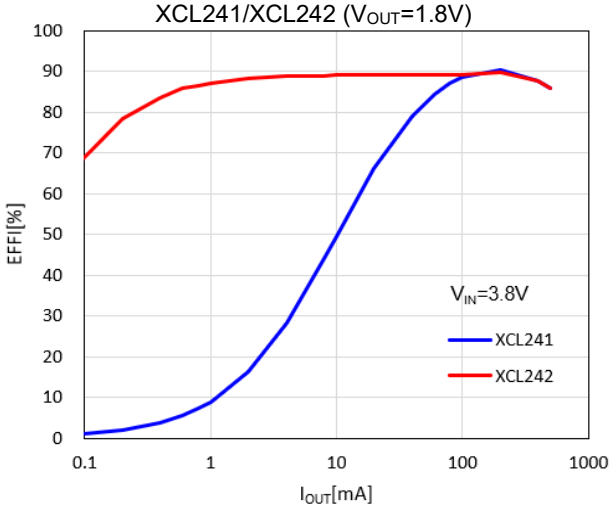
Input Voltage Range	:	2.5V ~ 5.5V
Output Voltage Range	:	0.8V ~ 1.0V (±20mV) 1.05V ~ 3.6V (±2.0%)
Output Current	:	500mA
Oscillation Frequency	:	1.2MHz
Efficiency	:	92% (V_{IN}=3.8V, V_{OUT}=1.8V, I_{OUT}=200mA)
Quiescent Current	:	15μA (XCL242)
Control Methods	:	HiSAT-COT Control PWM Control (XCL241) PWM/PFM Auto (XCL242)
Protection Functions	:	Thermal Shutdown Current Limit Short Protection
Functions	:	Soft-Start UVLO C_L Discharge
Input/Output Capacitor	:	Ceramic Capacitor
Operating Ambient Temperature	:	-40℃ ~ 105℃
Packages	:	CL-2025-02 (2.5 x 2.0 x h1.04mm)
Environmentally Friendly	:	EU RoHS Compliant, Pb Free

■TYPICAL APPLICATION CIRCUIT

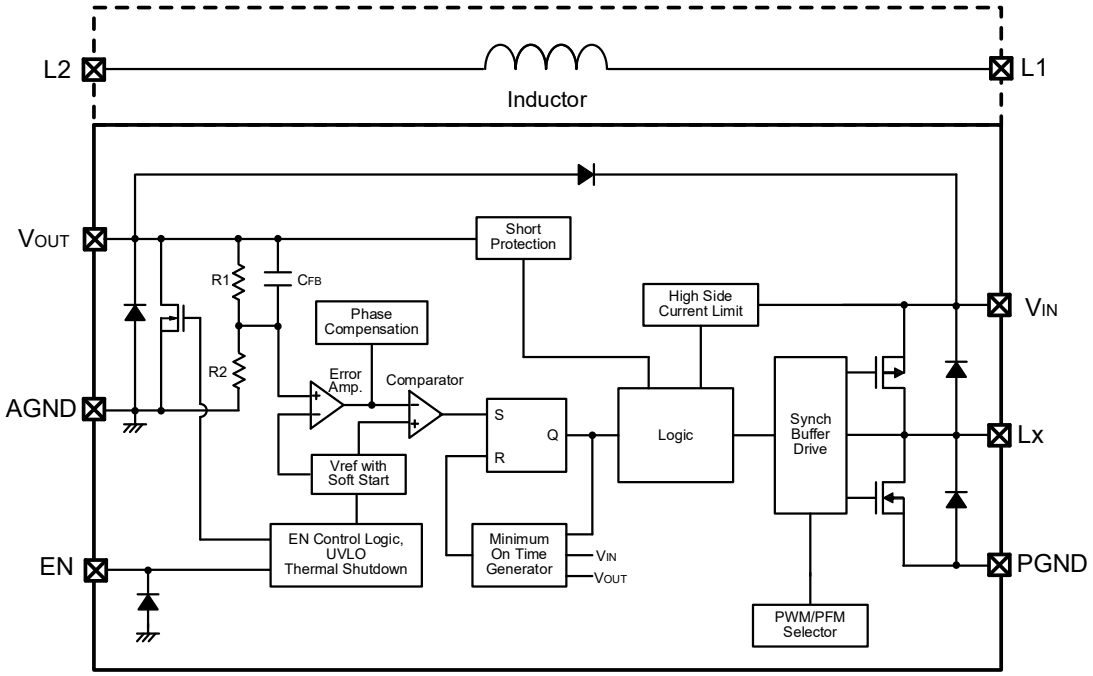


■ TYPICAL PERFORMANCE CHARACTERISTICS

XCL241/XCL242 (V_{OUT}=1.8V)



■BLOCK DIAGRAM



*"PWM/PFM Selector" in the XCL241 series is fixed to PWM control.
"PWM/PFM Selector" in the XCL242 series is fixed to PWM/PFM automatic switching control.
Diodes inside the circuit are ESD protection diodes and parasitic diodes.

■PRODUCT CLASSIFICATION

●Ordering Information

XCL241①②③④⑤⑥-⑦ : PWM control

XCL242①②③④⑤⑥-⑦ : PWM/PFM Automatic switching control

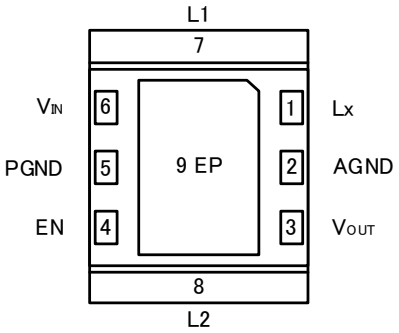
DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	B	Refer to Selection Guide
②③	Output Voltage	08 ~ 36	Output voltage e.g. 1.2V → ②=1, ③=2 1.25V → ②=1, ③=C 0.05V increments : 0.05=A, 0.15=B, 0.25=C, 0.35=D, 0.45=E, 0.55=F, 0.65=H, 0.75=K, 0.85=L, 0.95=M
④	Oscillation Frequency	1	1.2MHz
⑤⑥-⑦(*1)	Package (Order Unit)	KR-G	CL-2025-02 (3,000pcs/Reel)

(*1) The “-G” suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

●Selection Guide

FUNCTION	B TYPE
Enable	Yes
UVLO	Yes
Soft-Start Time	Fixed
C_L Discharge	Yes
Current Limit (Automatic Recovery)	Yes
Short Protection (Latch Protection)	Yes
Thermal Shutdown	Yes

■PIN CONFIGURATION



< BOTTOM VIEW >

* PIN2 and PIN5 terminals must be connected to GND.

■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTIONS
1	Lx	Switching
2	AGND	Analog Ground
3	V_{OUT}	Output Voltage
4	EN	Enable
5	PGND	Power Ground
6	V_{IN}	Input Voltage
7	L1	Inductor Electrodes
8	L2	Inductor Electrodes
9	EP	Exposed thermal pad. The Exposed pad must be connected to GND(Pin2, Pin5)

■ FUNCTION TABLE

PIN NAME	SIGNAL	STATUS
EN	L	Stand-by
	H	Active
	OPEN	Undefined State (*)

* Please do not leave the EN pin open.

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNITS
V_{IN} Pin Voltage	V_{IN}	-0.3 ~ 6.2	V
Lx Pin Voltage	V_{Lx}	-0.3 ~ V_{IN} + 0.3 or 6.2 (*1)	V
V_{OUT} Pin Voltage	V_{OUT}	-0.3 ~ V_{IN} + 0.3 or 4.0 (*2)	V
EN Pin Voltage	V_{EN}	-0.3 ~ 6.2	V
Power Dissipation(Ta=25℃)	Pd	1000 (High heat dissipation board) (*3)	mW
Junction Temperature	Tj	-40 ~ 125	℃
Storage Temperature	T_{stg}	-55 ~ 125	℃

All voltages are described based on the GND (AGND and PGND) pin.
(*1) The maximum value should be either V_{IN}+0.3V or 6.2V in the lowest voltage.
(*2) The maximum value should be either V_{IN}+0.3V or 4.0V in the lowest voltage.
(*3) The power dissipation figure shown is PCB mounted and is for reference only.
Please refer to PACKAGING INFORMATION for the mounting condition.

■RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Input Voltage	V_{IN}	2.5	-	5.5	V
EN Pin Voltage	V_{EN}	0.0	-	5.5	V
Output Current	I_{OUT}	-	-	500	mA
Operating Ambient Temperature	Topr	-40	-	105	℃
Input Capacitor (Effective Value) (*1)	C_{IN}	2.5	4.7	1000 (*2)	μF
Output Capacitor (Effective Value) (*1)	C_L	5.8	10	220 (*3)	μF

All voltages are described based on the AGND and PGND pin.

(*1) Some ceramic capacitors have an effective capacitance that is significantly lower than the nominal value due to the applied DC bias and ambient temperature. For the input / output capacitance of this IC, use an appropriate ceramic capacitor according to the DC bias usage conditions (ambient temperature, input / output voltage) so that the effective capacitance value is equal to or higher than the recommended component.

(*2) If using a large-capacity capacitor such as an electrolytic capacitor or tantalum capacitor as the input capacitance, place a low ESR ceramic capacitor in parallel. If a ceramic capacitor is not placed, high-frequency voltage fluctuations will increase and the IC may malfunction.

(*3) If using a large-capacity capacitor as the output capacitance, the output voltage may not rise during the soft-start time and the short protection function will operate after the soft-start time, causing the IC to latch and stop.

■ ELECTRICAL CHARACTERISTICS

Ta=25℃

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUIT
Output Voltage	V_{OUT}	V_{IN}=$V_{OUT(T)}$+2.0V($V_{OUT(T)}$≦3.5V) or 5.5V($V_{OUT(T)}$>3.5V), V_{OUT}=<E-3>→<E-1> V_{OUT} Voltage When Lx pin is V_{IN} or oscillations	<E-1>	<E-2>	<E-3>	V	①
Operating Voltage Range	V_{IN}		2.5	-	5.5	V	①
Maximum Output Current	I_{OUTMAX}	When connected to external components, V_{IN} =<C-1>	500	-	-	mA	①
UVLO Detect Voltage	V_{UVLOD}	V_{IN} = 2.5V to 1.2V, V_{OUT} = 0.6V, V_{IN} Voltage when Lx pin changes “H” to "L" level	1.35	1.95	-	V	③
UVLO Release Voltage	V_{UVLOR}	V_{IN} = 1.2V to 2.5V, V_{OUT} = 0.6V, V_{IN} Voltage when Lx pin changes “L” to "H" level	-	2.00	2.48	V	③
Quiescent Current (XCL242)	I_q	V_{OUT} =$V_{OUT(T)}$ ×1.1	-	15	25	μA	②
Quiescent Current (XCL241)	I_q	V_{OUT} =$V_{OUT(T)}$ ×1.1	-	250	455	μA	②
Stand-by Current	I_{STB}	V_{EN} =0V	-	0.0	1.0	μA	②
Minimum ON time (*2)	t_{ONmin}	When connected to external components, V_{IN} =V_{EN}=<C-1>, I_{OUT}=1mA	<E-5>	<E-6>	<E-7>	ns	①
Thermal Shutdown	T_{TSD}		-	150	-	℃	①
Thermal shutdown Hysteresis	T_{HYS}		-	30	-	℃	①
Lx SW ”H” ON Resistance	R_{LXH}	V_{OUT}=0.6V, I_{LX}=100mA	-	0.24	0.44	Ω	④
Lx SW ”L” ON Resistance (*1)	R_{LXL}	V_{IN}=3.6V, V_{OUT}=$V_{OUT(T)}$ × 1.1, I_{LX}=100mA	-	0.16	0.34	Ω	④
Lx SW ”H” Leakage Current	I_{LeakH}	V_{IN}=5.5V, V_{EN}=0V, V_{OUT}=0V, V_{LX}=0V	-	0.0	1.0	μA	⑤
Lx SW ”L” Leakage Current	I_{LeakL}	V_{IN}=5.5V, V_{EN}=0V, V_{OUT}=0V, V_{LX}=5.5V	-	0.0	1.0	μA	⑤
Current Limit (*2)	I_{LIMH}	V_{OUT}=0.6V, I_{Lx} until Lx pin oscillates	1.3 (*1)	1.5	2.5 (*1)	A	⑥
Output Voltage Temperature Characteristics	ΔV_{OUT}/ (V_{OUT}・Δtopr)	I_{OUT}=30mA -40℃≦Topr≦105℃	-	±100	-	ppm/℃	①
EN ”H” Voltage	V_{ENH}	V_{OUT}=0.6V, Applied voltage to V_{EN}, Voltage changes Lx to “H” level — Ta=25℃	1.4	-	5.5	V	③
		V_{OUT}=0.6V, Applied voltage to V_{EN}, Voltage changes Lx to “H” level — Ta=-40~105℃(*1)					
EN ”L” Voltage	V_{ENL}	V_{OUT}=0.6V, Applied voltage to V_{EN}, Voltage changes Lx to “L” level — Ta=25℃	AGND	-	0.3	V	③
		V_{OUT}=0.6V, Applied voltage to V_{EN}, Voltage changes Lx to “L” level — Ta=-40~105℃(*1)					
EN ”H” Current	I_{ENH}	V_{IN}=5.5V, V_{EN}=5.5V, V_{OUT}=0V	-	0.0	0.1	μA	⑤
EN ”L” Current	I_{ENL}	V_{IN}=5.5V, V_{EN}=0V, V_{OUT}=0V	-	0.0	0.1	μA	⑤
Soft-start Time	t_{SS}	V_{EN}=0V→5.0V, V_{OUT}=$V_{OUT(T)}$ × 0.9 After "H" is fed to EN, the time by when clocks are generated at Lx pin.	0.10	0.30	0.60	ms	③
Short Protection Threshold Voltage	V_{SHORT}	Sweeping V_{OUT}, V_{OUT} voltage which Lx becomes “L” level	0.17	0.27	0.38	V	③
C_L Discharge Resistance	R_{DCHG}	V_{EN}=0V, V_{OUT}=4.0V	100	180	300	Ω	⑦
Inductance	L	Test Freq.=1MHz	-	2.2	-	μH	-

$V_{OUT(T)}$: Nominal Voltage

Unless otherwise stated, V_{IN}=5.0V, V_{EN}=5.0V, "H" level = V_{IN} - 1.2V ~ V_{IN}, "L" level = -0.1V ~ 0.1V

(*1) Design value.

(*2) Current limit denotes the level of detection at peak of Inductor current.

■ELECTRICAL CHARACTERISTICS (Continued)

●SPEC Table

NOMINAL OUTPUT VOLTAGE	V_{OUT}			t_{ON}			
	<E-1>	<E-2>	<E-3>	<C-1>	<E-5>	<E-6>	<E-7>
$V_{OUT(T)}$	MIN.	TYP.	MAX.	V_{IN}	MIN.	TYP.	MAX.
0.80	0.780	0.800	0.820	2.50	183	267	350
0.85	0.830	0.850	0.870	2.50	197	283	370
0.90	0.880	0.900	0.920	2.50	210	300	390
0.95	0.930	0.950	0.970	2.50	223	317	410
1.00	0.980	1.000	1.020	2.50	237	333	430
1.05	1.029	1.050	1.071	2.50	268	350	433
1.10	1.078	1.100	1.122	2.50	282	367	452
1.15	1.127	1.150	1.173	2.50	296	383	471
1.20	1.176	1.200	1.224	2.50	310	400	490
1.25	1.225	1.250	1.275	2.50	324	417	509
1.30	1.274	1.300	1.326	2.50	338	433	528
1.35	1.323	1.350	1.377	2.50	353	450	548
1.40	1.372	1.400	1.428	2.50	367	467	567
1.45	1.421	1.450	1.479	2.50	381	483	586
1.50	1.470	1.500	1.530	2.50	395	500	605
1.55	1.519	1.550	1.581	2.58	395	500	605
1.60	1.568	1.600	1.632	2.67	395	500	605
1.65	1.617	1.650	1.683	2.75	395	500	605
1.70	1.666	1.700	1.734	2.83	395	500	605
1.75	1.715	1.750	1.785	2.92	395	500	605
1.80	1.764	1.800	1.836	3.00	395	500	605
1.85	1.813	1.850	1.887	3.08	395	500	605
1.90	1.862	1.900	1.938	3.17	395	500	605
1.95	1.911	1.950	1.989	3.25	395	500	605
2.00	1.960	2.000	2.040	3.33	395	500	605
2.05	2.009	2.050	2.091	3.42	395	500	605
2.10	2.058	2.100	2.142	3.50	395	500	605
2.15	2.107	2.150	2.193	3.58	395	500	605
2.20	2.156	2.200	2.244	3.67	395	500	605
2.25	2.205	2.250	2.295	3.75	395	500	605
2.30	2.254	2.300	2.346	3.83	395	500	605
2.35	2.303	2.350	2.397	3.92	395	500	605
2.40	2.352	2.400	2.448	4.00	395	500	605
2.45	2.401	2.450	2.499	4.08	395	500	605
2.50	2.450	2.500	2.550	4.17	395	500	605
2.55	2.499	2.550	2.601	4.25	395	500	605
2.60	2.548	2.600	2.652	4.33	395	500	605
2.65	2.597	2.650	2.703	4.42	395	500	605
2.70	2.646	2.700	2.754	4.50	395	500	605

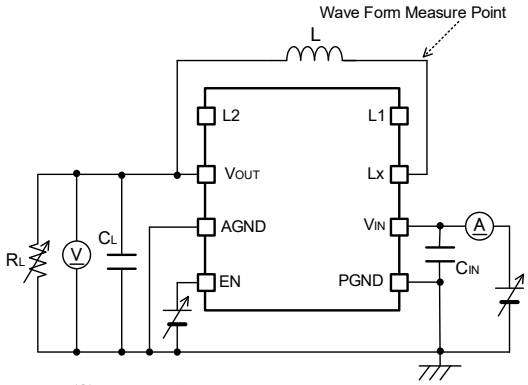
■ELECTRICAL CHARACTERISTICS (Continued)

●SPEC Table

NOMINAL OUTPUT VOLTAGE	V_{OUT}			t_{ON}			
	<E-1>	<E-2>	<E-3>	<C-1>	<E-5>	<E-6>	<E-7>
$V_{OUT(T)}$	MIN.	TYP.	MAX.	V_{IN}	MIN.	TYP.	MAX.
2.75	2.695	2.750	2.805	4.58	395	500	605
2.80	2.744	2.800	2.856	4.67	395	500	605
2.85	2.793	2.850	2.907	4.75	395	500	605
2.90	2.842	2.900	2.958	4.83	395	500	605
2.95	2.891	2.950	3.009	4.92	395	500	605
3.00	2.940	3.000	3.060	5.00	395	500	605
3.05	2.989	3.050	3.111	5.08	395	500	605
3.10	3.038	3.100	3.162	5.17	395	500	605
3.15	3.087	3.150	3.213	5.25	395	500	605
3.20	3.136	3.200	3.264	5.33	395	500	605
3.25	3.185	3.250	3.315	5.42	395	500	605
3.30	3.234	3.300	3.366	5.50	395	500	605
3.35	3.283	3.350	3.417	5.50	401	500	614
3.40	3.332	3.400	3.468	5.50	408	515	622
3.45	3.381	3.450	3.519	5.50	414	523	631
3.50	3.430	3.500	3.570	5.50	421	530	640
3.55	3.479	3.550	3.621	5.50	427	538	649
3.60	3.528	3.600	3.672	5.50	434	545	657

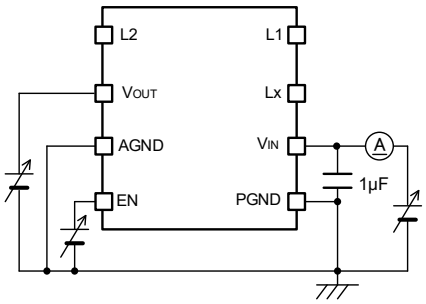
■TEST CIRCUITS

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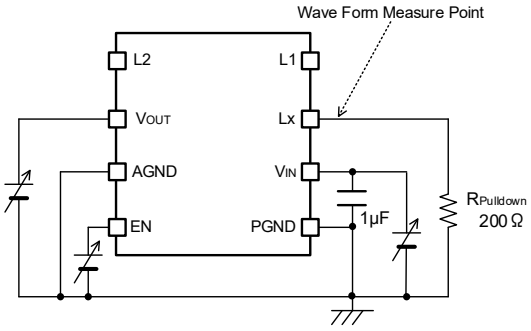


※External Components
L:2.2μH(Selected goods)
CIN:4.7μF(Ceramic)
CL:10μF(Ceramic)

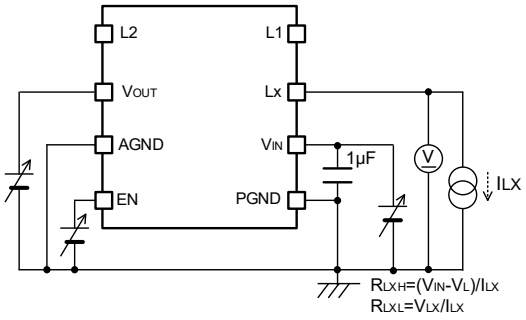
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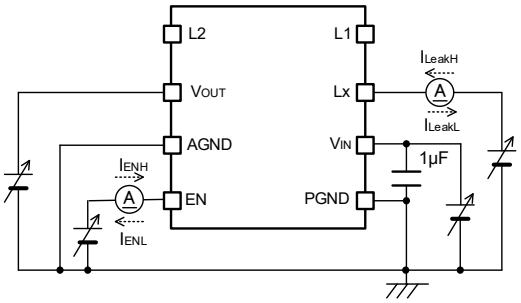
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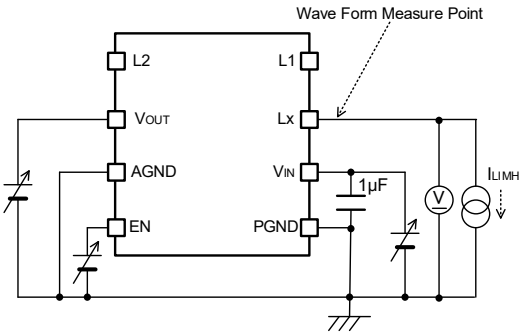
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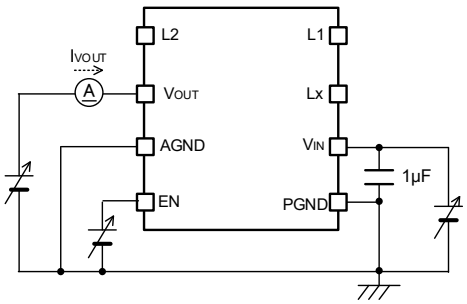
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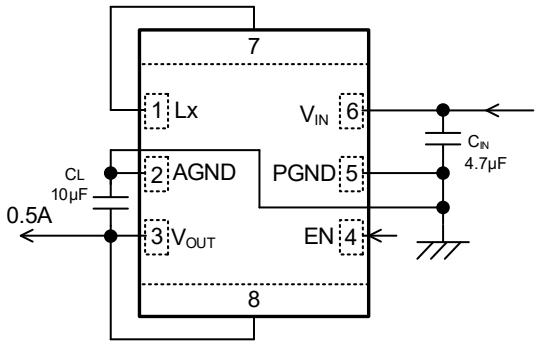
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< Circuit No.⑦ >



■TYPICAL APPLICATION CIRCUIT



【Typical Examples】

	MANUFACTURER	PRODUCT NUMBER	VALUE	SIZE(L×W×T)
C_{IN} (*1,2)	Murata	GRM188C81A475ME11	4.7μF/16V	1.6 x 0.8 x 1.0mm
		GRM188C81A106KA73D	10μF/10V	1.6 x 0.8 x 1.0mm
	Taiyo Yuden	MSAST168BB5475KTNA01	4.7μF/25V	1.6 x 0.8 x 1.0mm
		MSAST21GAB7475KTNA01	4.7μF/25V	2.0 x 1.25 x 1.4mm
	TDK	C1608X5R1E475K080AC	4.7μF/25V	1.6 x 0.8 x 0.9mm
		C2012X7R1E475K125AB	4.7μF/25V	2.0 x 1.25 x 1.45mm
C_L (*1,3)	Murata	GRM188C81A106KA73D	10μF/10V	1.6 x 0.8 x 1.0mm
	Taiyo Yuden	MSAST168BB5106MTNA01	10μF/25V	1.6 x 0.8 x 1.0mm
		MSASL21GAB7106KTNA01	10μF/10V	2.0 x 1.25 x 1.4mm
	TDK	C1608X5R1E106M080AC	10μF/25V	1.6 x 0.8 x 1.0mm
		C2012X7R1A106K125AC	10μF/10V	2.0 x 1.25 x 1.45mm

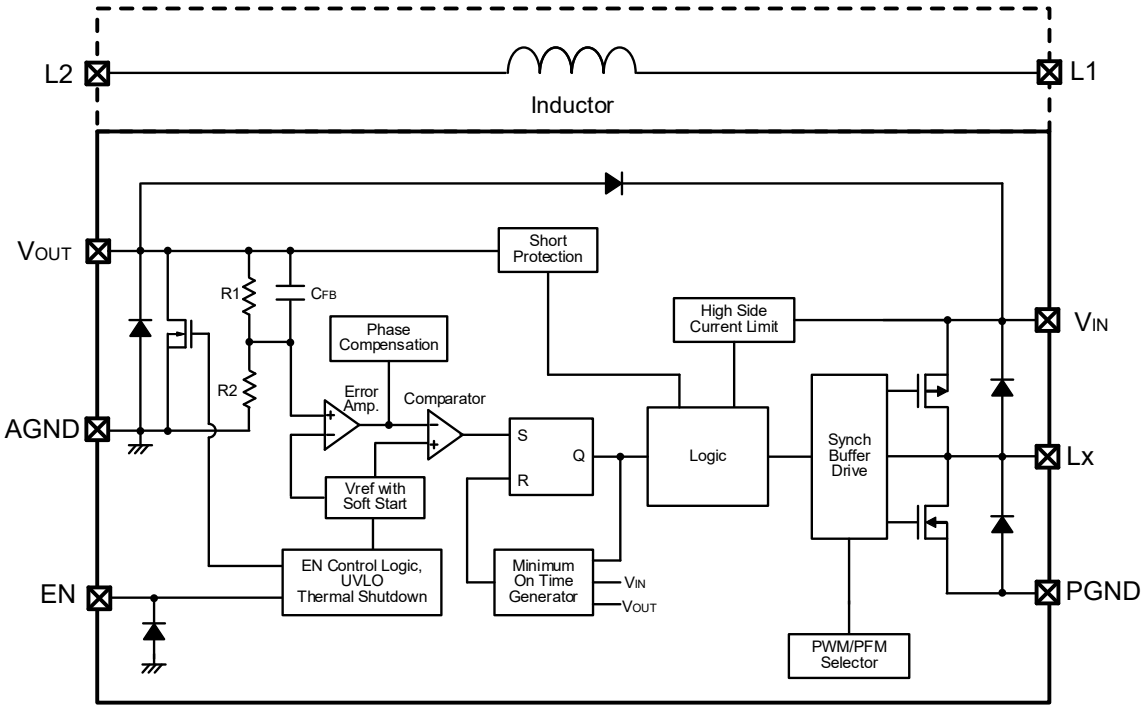
(*1) Some ceramic capacitors have an effective capacitance that is significantly lower than the nominal value due to the applied DC bias and ambient temperature. For the input / output capacitance of this IC, use an appropriate ceramic capacitor according to the DC bias usage conditions (ambient temperature, input / output voltage) so that the effective capacitance value is equal to or higher than the recommended component.

(*2) If using a large-capacity capacitor such as an electrolytic capacitor or tantalum capacitor as the input capacitance, place a low ESR ceramic capacitor in parallel. If a ceramic capacitor is not placed, high-frequency voltage fluctuations will increase and the IC may malfunction.

(*3) If using a large-capacity capacitor as the output capacitance, the output voltage may not rise during the soft-start time and the short protection function will operate after the soft-start time, causing the IC to latch and stop.

■OPERATIONAL EXPLANATION

This IC consists of a reference voltage source, error amplifier, comparator, phase compensation, on time generation circuit, current limiter circuit, UVLO circuit and so on.



BLOCK DIAGRAM

The control method is HiSAT-COT (High Speed circuit Architecture for Transient with Constant On Time), which features the On time control method and the fast transient response with low ripple voltage.

■OPERATIONAL EXPLANATION (Continued)

＜Nomal operation＞

In HiSAT-COT control, ON time (t_{ON}) dependent on input voltage and output voltage is generated and Pch driver FET is turned on.

The on-time is set as follows during light loads.

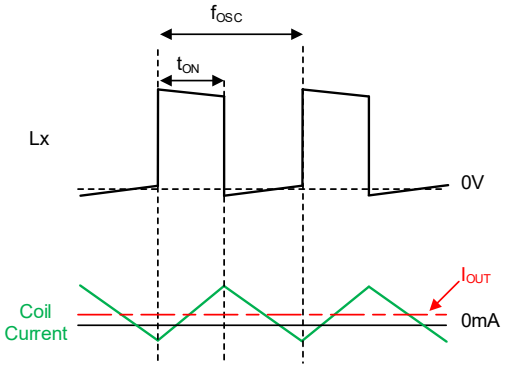
$$t_{ON} = (V_{OUT} / V_{IN}) \times 833ns$$

The off time (t_{OFF}) is controlled by comparing the output voltage with the reference voltage using the error amplifier and comparator. Specifically, the reference voltage and a voltage which is obtained by dividing the output voltage with R1 and R2 are compared either use with or using in the sentence, phase compensation is applied to the error amplifier output and sent to the comparator. In the comparator, the output of the error amplifier is compared with the reference voltage, and when it falls below the reference voltage, the SR latch is set and it becomes the ON period again.

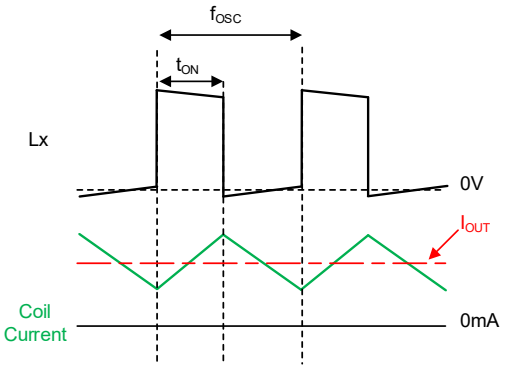
PWM control

The XCL239 series (PWM control) operates in continuous conduction mode and operates at a stable oscillation frequency regardless of the load. The oscillation frequency can be obtained by the following equation.

$$f_{OSC} = (V_{OUT} / V_{IN}) \times (1 / t_{ON})$$



XCL241 series: Example of light load operation

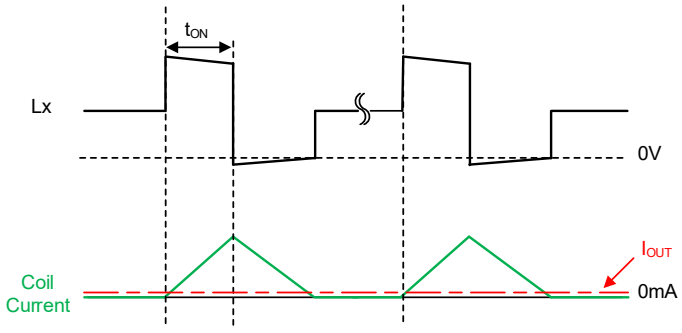


XCL241 series: Example of heavy load operation

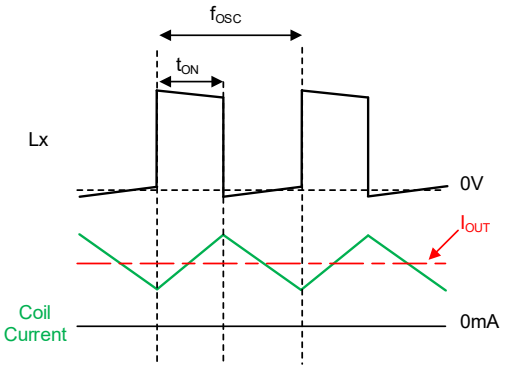
PWM/PFM automatic switching control

The XCL240 series (PWM/PFM automatic switching control) lowers the oscillation frequency at light load by operating in discontinuous conduction mode at light load.

As the output current increases, the switching frequency increases proportionally. By this operation, it is possible to reduce switching loss at light load and achieve high efficiency from light load to heavy load.



XCL242 series: Example of light load operation



XCL242 series: Example of heavy load operation

■OPERATIONAL EXPLANATION (Continued)

＜100% Duty cycle mode＞

In conditions where the input-output voltage difference is small or during transient response, the Pch driver FET may be in 100% duty cycle mode.

The 100% duty cycle mode achieves highspeed response and output voltage stability under the condition where input-output voltage difference is small.

＜EN function＞

When "H" voltage (V_{ENH}) is fed to the EN pin, normal operation starts after raising the output voltage with the soft-start function. When the "L" voltage (V_{ENL}) is fed to the EN pin, it enters the stand-by state and the current consumption is suppressed to I_{STB} (TYP. 0.0μA).

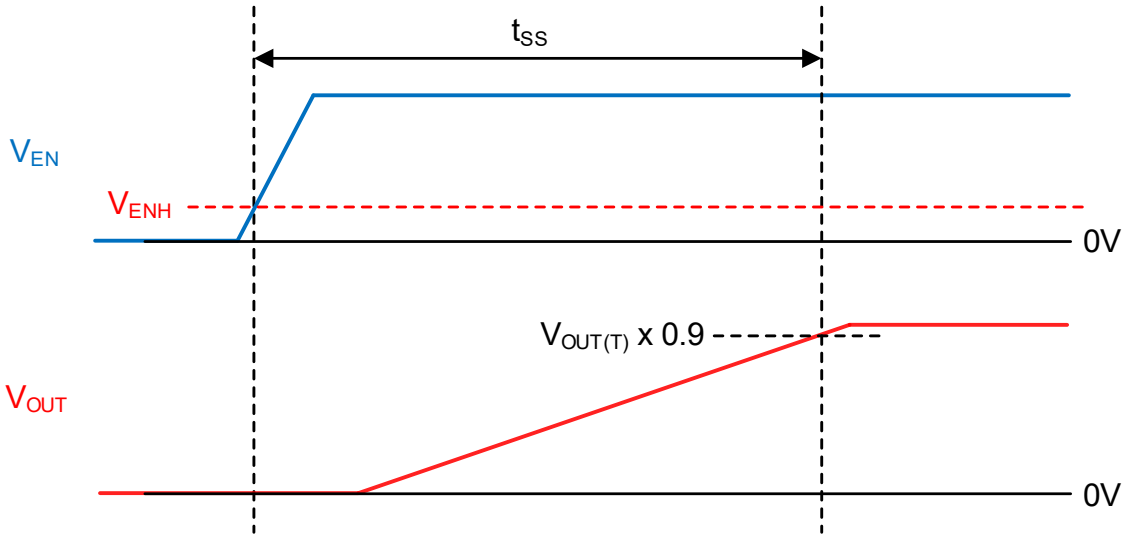
Additionally, Pch driver FET and Nch driver FET are turned off.

＜Start Mode / Soft-Start function＞

It is a function to raise the output voltage gradually and suppress inrush current. After the "H" voltage (V_{ENH}) is fed to the EN pin, the reference voltage which is connected to the error amplifier increases linearly during the soft-start period. As a result, the output voltage increases in proportion to the increase of the reference voltage. This operation can prevent a large inrush current and smoothly raise the output voltage.

During the soft-start function, short protection does not work.

Also, even with PWM control, reverse inductor current is prohibited.



■OPERATIONAL EXPLANATION (Continued)

＜Current Limit / Short protection＞

The current limit function monitors the current flowing through Pch driver FET in each switching cycle and when Pch driver current is more than I_{LIMH} (TYP. 1.5A), an overcurrent detection state occurs.

When the overcurrent detection state occurs, the Pch driver FET is turned off. If the current flowing through Pch driver FET is less than I_{LIMH} in the next switching cycle, the overcurrent detection state is released.

If the overcurrent detection state continues or if there is a significant drop in the output voltage, the B type short-circuit protection function will operate.

The detailed operation at overcurrent is as follows.

1) When the current flowing through the Pch driver FET increases and reaches the current limit value I_{LIMH} (TYP. 1.5A), the current limit state is set and the Pch driver FET is forcibly turned off.

2) After the Pch driver FET is turned off, the Nch driver FET is turned on for a certain period of time, and the inductor current decreases. If there is an overload state, the Pch driver FET will turn on again until inductor current reaches the current limit value.

3) Further reducing the load resistance will drop output voltage.
When the output voltage drops, the inductor current does not decrease during the Nch Driver FET on period, and when the Pch driver turns on again, inductor current will increase more than the current limit value I_{LIMH}. When the inductor current flowing through the Nch driver FET increases, the Pch driver FET is prohibited to turn on until the current flowing through the Nch driver FET drops to I_{LIML} (TYP. 2.0A).

4) When the output voltage drops below short protection voltage V_{SHORT} (TYP. 0.27V) in an overload condition,
The short protection function is activated, and the P-channel driver FET and N-channel driver FET are latched in the off state.

■OPERATIONAL EXPLANATION (Continued)

＜Current Limit / Short protection (Continued)＞

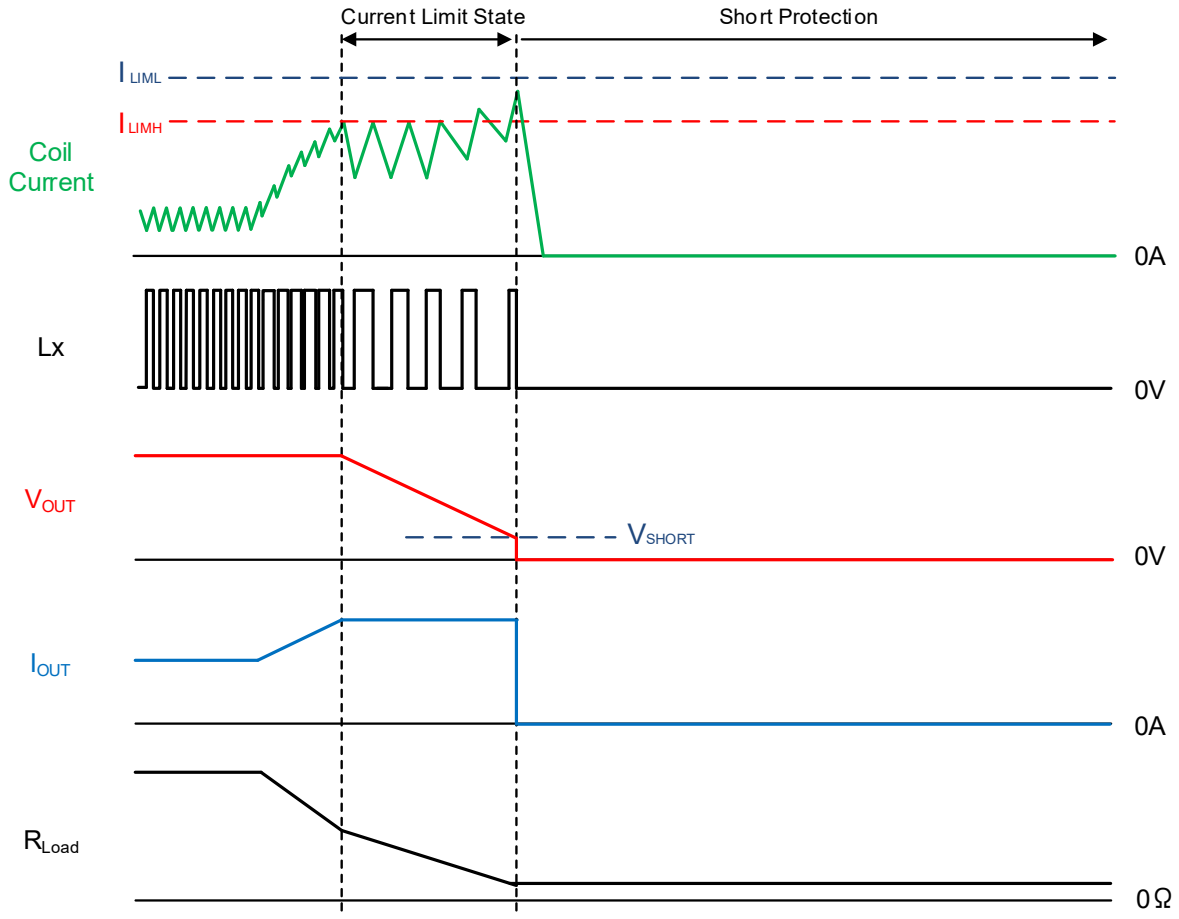
■Conditions for reversion from latch stop.

There are two conditions for returning from latch stop due to Short protection.

・Input “L” voltage to the EN pin to put it into stand-by state and then put IC into active state.

・After the input voltage is reduced to the UVLO detection state, a voltage higher than V_{UVLOR} is applied to the input voltage and the input voltage is set to the normal state.

To recover from latch stop, the output voltage is raised with the soft-start function, and then normal operation is performed. If the overload condition continues, the IC enters the current limit condition again and the current limit function and short protection is activated.



■OPERATIONAL EXPLANATION (Continued)

＜Thermal Shutdown function＞

The Junction temperature is monitored to protect the IC from thermal damage.

When the junction temperature reaches T_{TSD} (TYP. 150℃), thermal shutdown operates, the Pch driver FET and Nch driver FET are switched off and the output voltage drops. When the junction temperature drops to the thermal shutdown release temperature T_{TSD}-T_{HYS} (TYP. 120℃) by stopping the current supply, the output voltage is raised with the soft-start function, and then normal operation is performed.

＜UVLO function＞

When the V_{IN} voltage becomes V_{UVLOD} (TYP. 1.95V) or less, the UVLO function operates to forcibly turn off the Pch driver FET to prevent erroneous pulse output due to operation instability of the internal circuit.

When the V_{IN} voltage becomes V_{UVLOR} (TYP. 2.0V) or more, the UVLO function is canceled. After the UVLO function is canceled, the output voltage rises with the soft-start function, and then the normal operation is performed.

Moreover, during the UVLO operation, the internal circuit is operating because stopping by UVLO is not same to a stand-by mode and just switching operation is stopped.

＜C_L Discharge function＞

To prevent application malfunctions caused by charge remaining on the output capacitor (EN = "L") during stand-by, this IC uses an Nch FET and resistor connected to the V_{OUT} pin to rapidly discharge the charge on the output capacitor.

It also operates in the UVLO detection state.

The output voltage during discharging can be calculated by the following equation.

$$V = V_{OUT(T)} \times e^{-t/\tau}$$

$$t = \tau \ \ Ln\ (V_{OUT(T)} / V)$$

V	: Output voltage during discharge
$V_{OUT(T)}$	: Output voltage
t	: Discharge time
C_L	: Effective capacitance of Output capacitor
R_{DCHG}	: C_L auto-discharge resistance
τ	: $C_L \times R_{DCHG}$

■NOTE ON USE

1) For the phenomenon of temporal and transitional voltage decrease or voltage increase, the IC may be damaged or deteriorated if IC is used beyond the absolute MAX. specifications. Also, if used under out of the recommended operating range, the IC may not operate normally or may cause deterioration.

2) Spike noise and ripple voltage arise in a switching regulator as with a DC/DC converter. These are greatly influenced by external component selection, such as capacitance values, and board layout of external components. Once the design has been completed, verification with actual components should be done.

3) The DC/DC converter characteristics depend greatly on the externally connected components as well as on the characteristics of this IC, so refer to the specifications and standard circuit examples of each component when carefully considering which components to select. Especially for C_L capacitor, it is recommended to use an appropriate ceramic capacitor according to the DC bias usage conditions (ambient temperature, input / output voltage) so that the effective capacitance value is equal to or higher than the recommended component.

4) Due to propagation delay inside the product, the on time generated by the on time generation circuit is not the same as the on time that is the ratio of the input voltage to the output voltage.

5) The actual inductor current may at times exceed the current limit value (I_{LIMH}) due to propagation delays in the current limiting circuit.

6) Regarding PWM/PFM auto switching control method, it works with a discontinuous conduction mode at light loads, and in this case where the voltage difference between input voltage and output voltage is low, the inductor current may reverse when the load is light, and thus pulse skipping will not be possible and light load efficiency will worsen.

7) When the voltage difference between input voltage and output voltage is low, the load stability feature may deteriorate.

8) Torex places an importance on improving our products and their reliability. We request that users incorporate fail safe designs and post aging protection treatment when using Torex products in their systems.

9) This IC is an Inductor Built-in product, do not place it in an environment with a strong magnetic field such as near a magnet. The influence of a strong magnetic field may cause a decrease in inductance value, deterioration of efficiency, and abnormal operation of the IC.

10) The coil is exclusively for this product. Please do not use it for any purpose other than this product.

11) Torex places an importance on improving our products and their reliability. We request that users incorporate fail-safe designs and post-aging protection treatment when using Torex products in their systems.

■NOTE ON USE (Continued)

●Instructions of board layout

The following items require special attention in the board layout.
Please refer to the reference pattern layout on the next page.

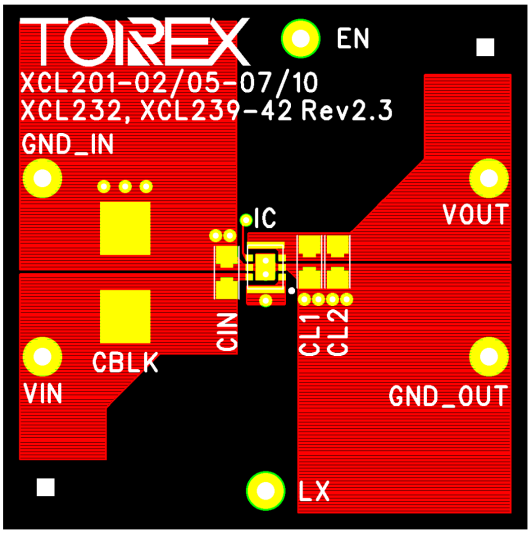
(a) Make the wiring of high current lines thicker and shorter.
This makes it possible to reduce the wire impedance, which is expected to reduce noise and improve heat dissipation. If the wire impedance of the large current line is large, this may cause noise generation or prevent the IC from operating properly.

(b) Place the input capacitance C_{IN}, output capacitance C_L, IC which the large current flows on the same surface. If they are placed on both sides, a large current will flow through Via, which has high impedance, it may cause noise and the IC may not operate normally.

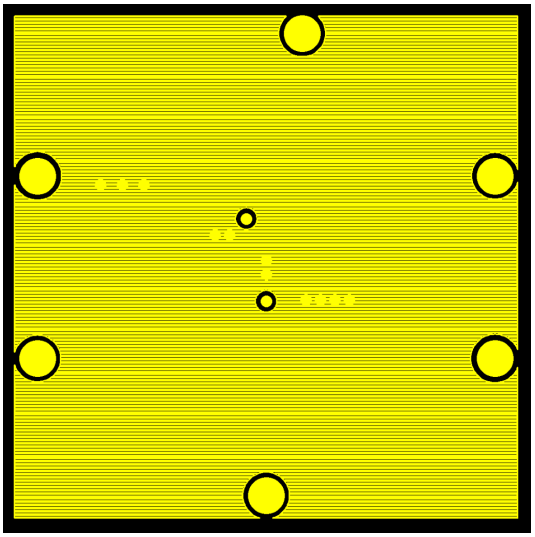
(c) Please mount each external component as close to the IC as possible.
Especially place the input capacitance C_{IN} near the IC and connect it with as low impedance as possible.
If the input capacity C_{IN} and IC are too far apart, it may cause noise or the IC may not operate normally.

<Reference board layout>

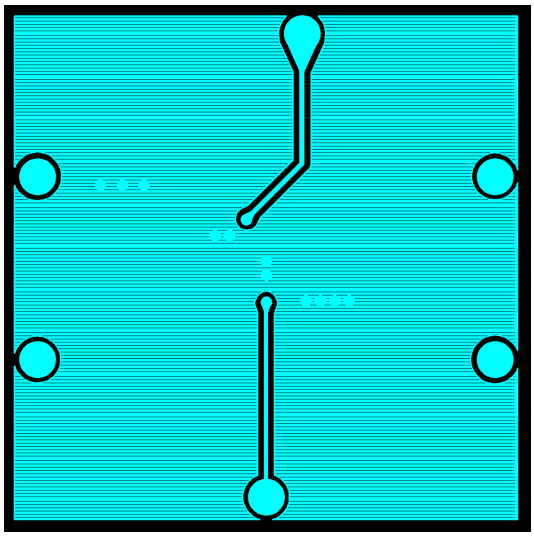
Layer 1



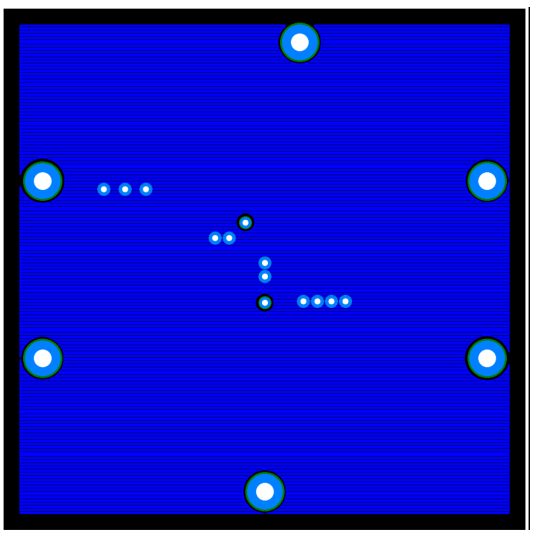
Layer 2



Layer 3



Layer 4



■Notes on handling of product

(1) The coil mounted on this product complies with the general surface mount type chip inductor specifications, and may have scratches, flux stains, etc.

(2) Do not use this product in the following environments. Places exposed to water or salt water, places where condensation occurs, places where toxic gases (hydrogen sulfide, zinc acid, chlorine, ammonia, etc.) are present.

(3) Please do not wash this product with solvent.

■Notes on mounting

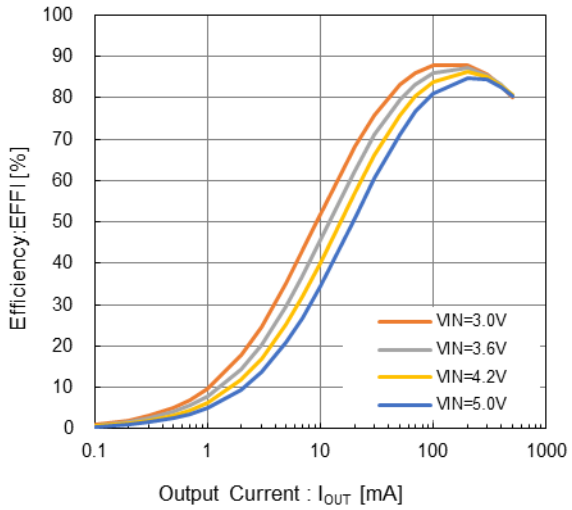
(1) Mounting accuracy of 0.05 mm or less is recommended.

(2) The proper position of mounting is based on the coil terminal

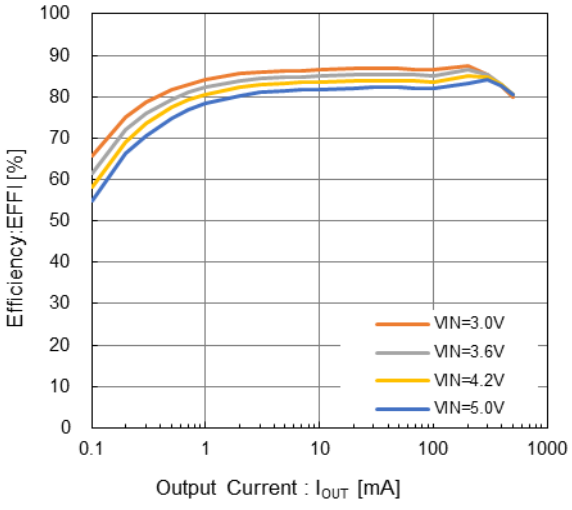
■TYPICAL PERFORMANCE CHARACTERISTICS

(1) Efficiency vs. Output Current

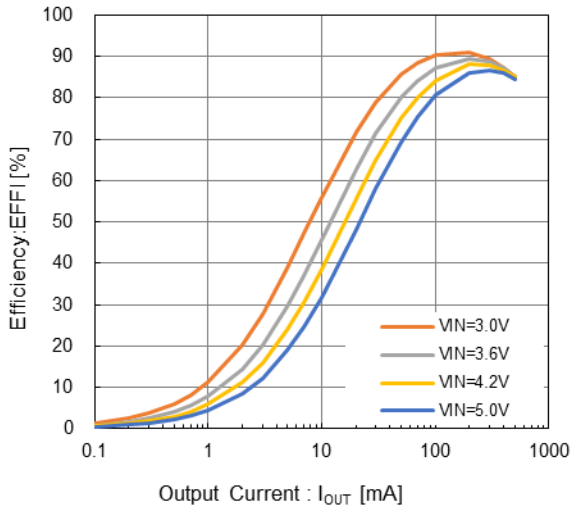
XCL241 $V_{OUT(T)}$=1.2V



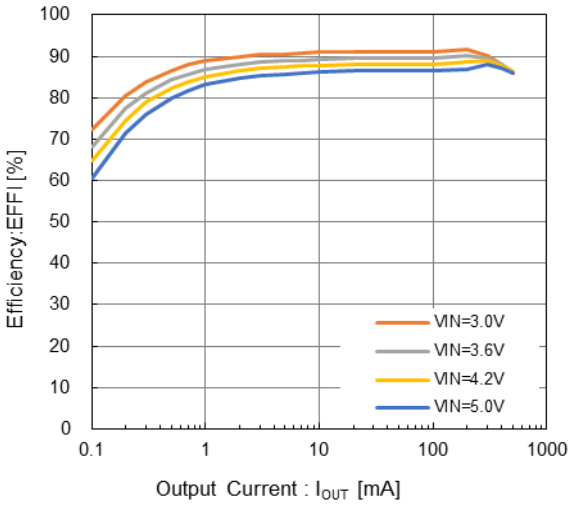
XCL242 $V_{OUT(T)}$=1.2V



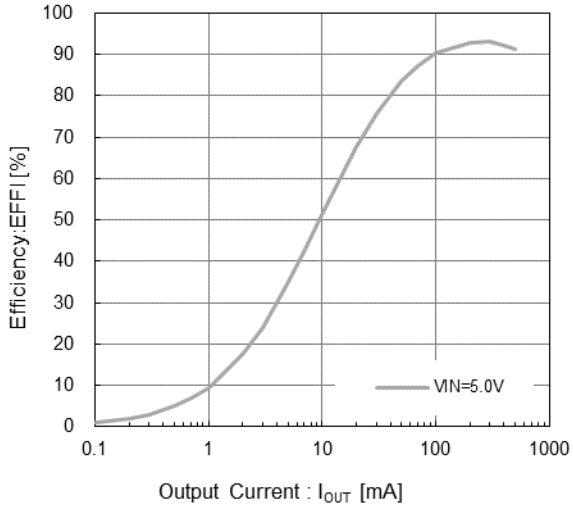
XCL241 $V_{OUT(T)}$=1.8V



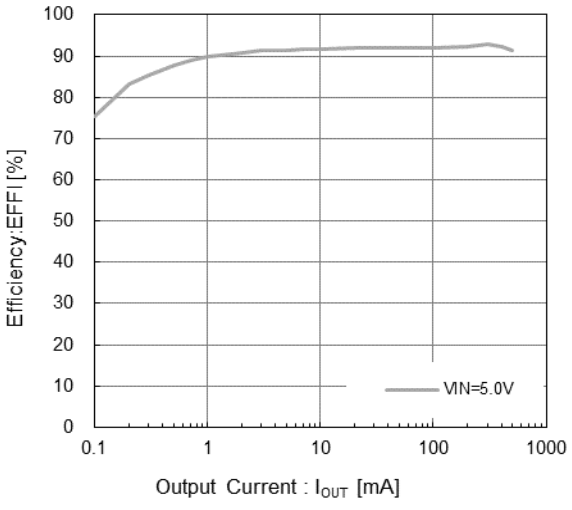
XCL242 $V_{OUT(T)}$=1.8V



XCL241 $V_{OUT(T)}$=3.3V



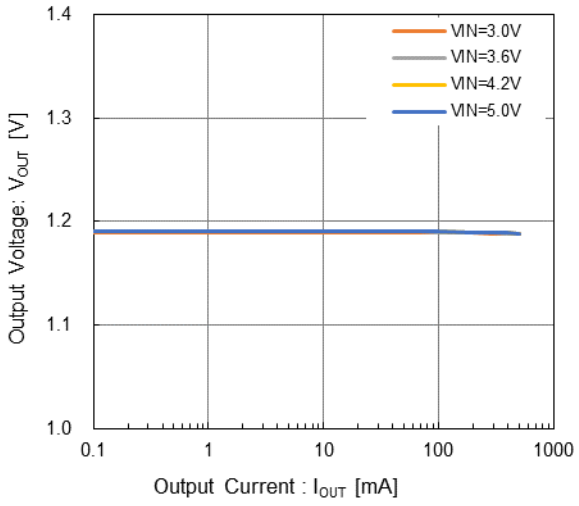
XCL242 $V_{OUT(T)}$=3.3V



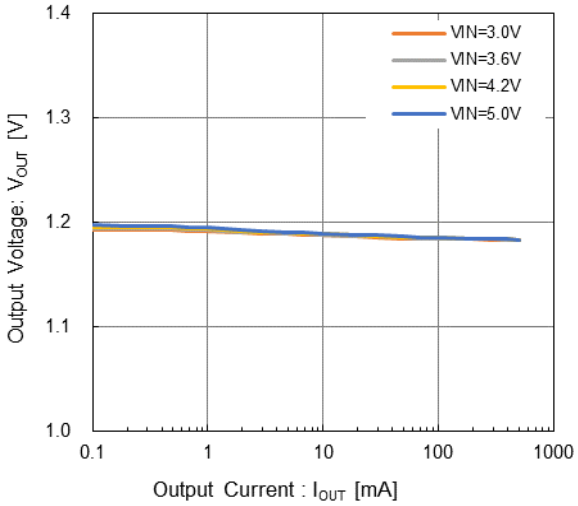
■TYPICAL PERFORMANCE CHARACTERISTICS

(2) Output Voltage vs. Output Current

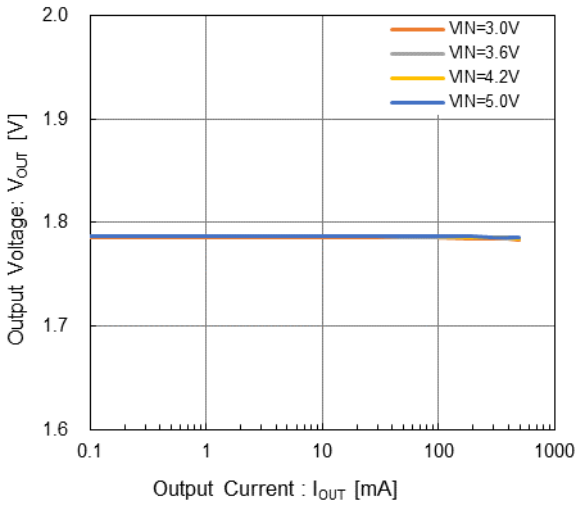
XCL241 $V_{OUT(T)}$=1.2V



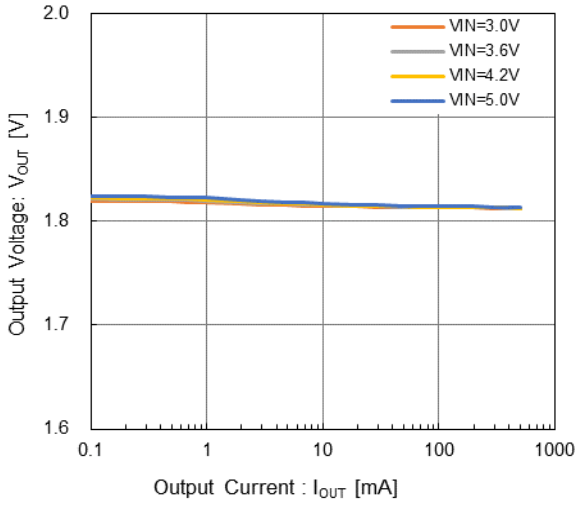
XCL242 $V_{OUT(T)}$=1.2V



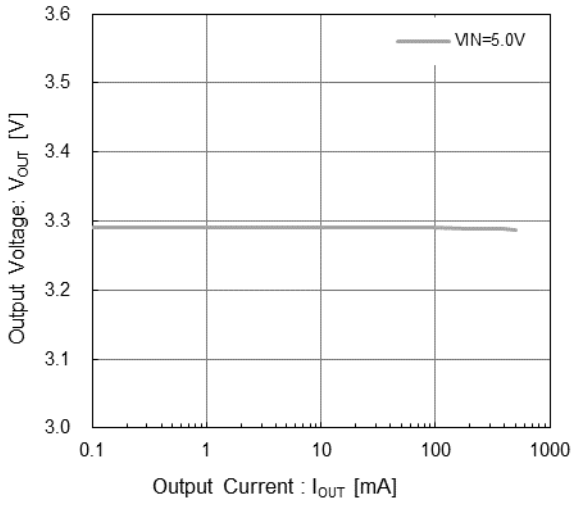
XCL241 $V_{OUT(T)}$=1.8V



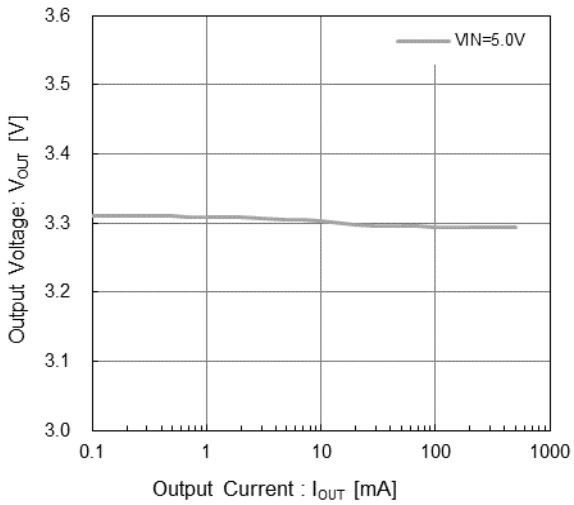
XCL242 $V_{OUT(T)}$=1.8V



XCL241 $V_{OUT(T)}$=3.3V



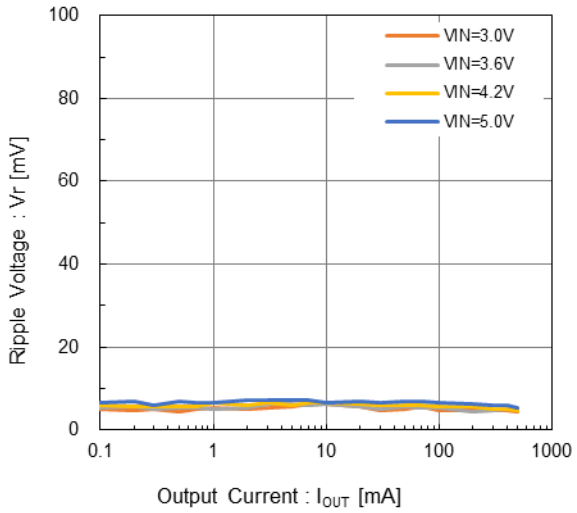
XCL242 $V_{OUT(T)}$=3.3V



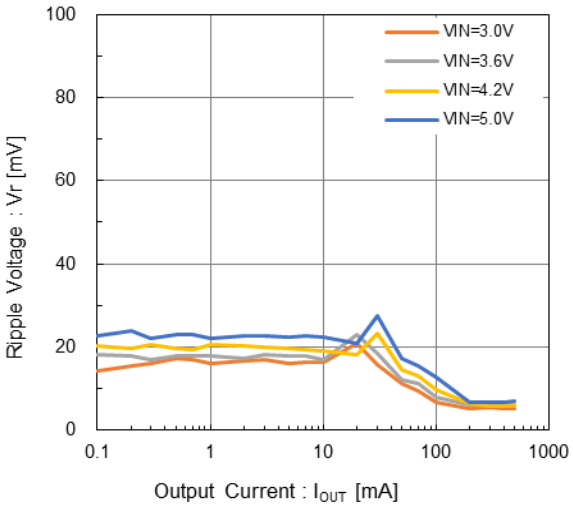
■TYPICAL PERFORMANCE CHARACTERISTICS

(3) Ripple Voltage vs. Output Current

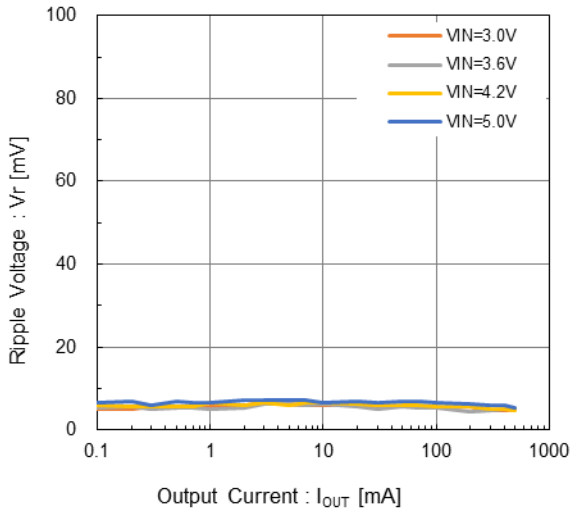
XCL241 $V_{OUT(T)}$=1.2V



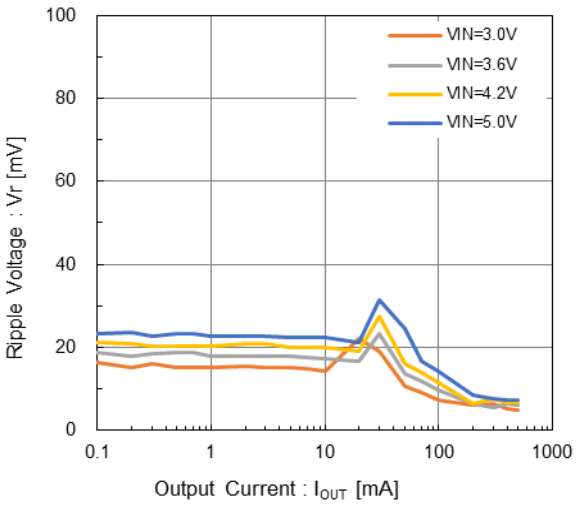
XCL242 $V_{OUT(T)}$=1.2V



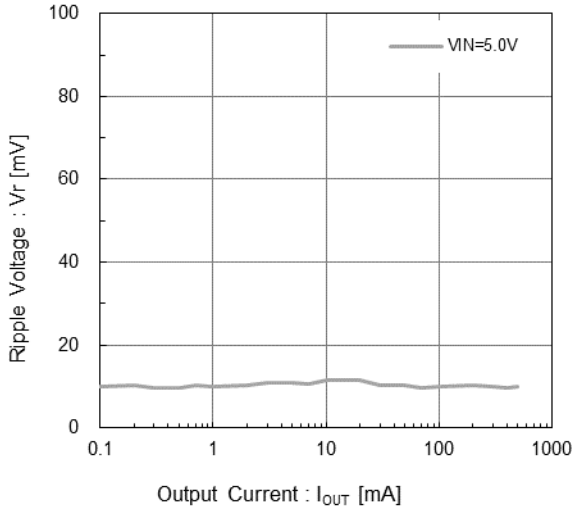
XCL241 $V_{OUT(T)}$=1.8V



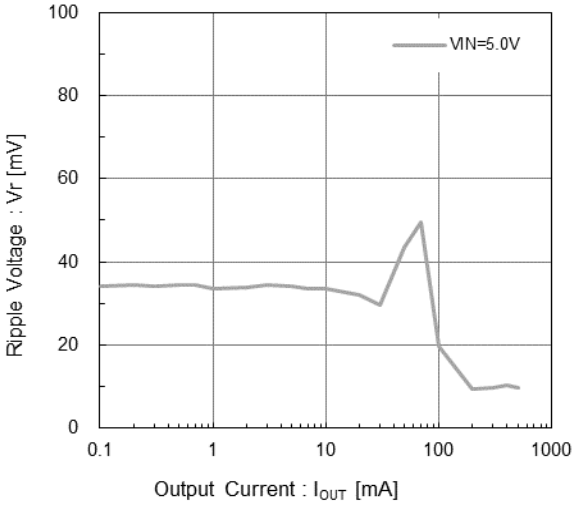
XCL242 $V_{OUT(T)}$=1.8V



XCL241 $V_{OUT(T)}$=3.3V



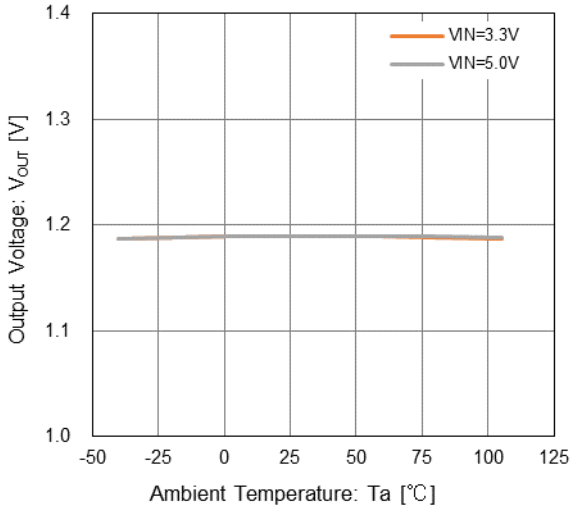
XCL242 $V_{OUT(T)}$=3.3V



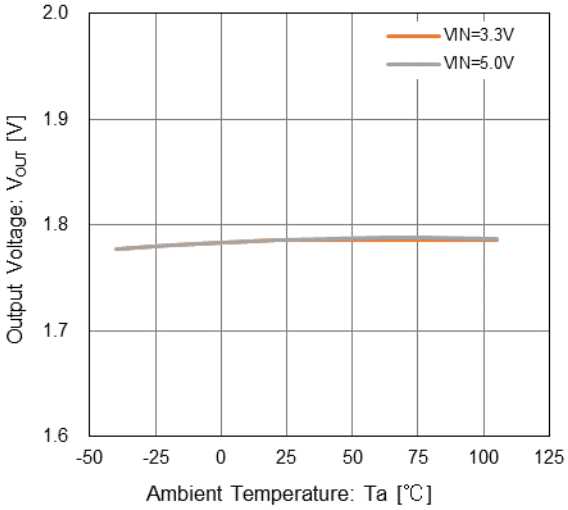
■TYPICAL PERFORMANCE CHARACTERISTICS

(4) Output Voltage vs. Ambient Temperature

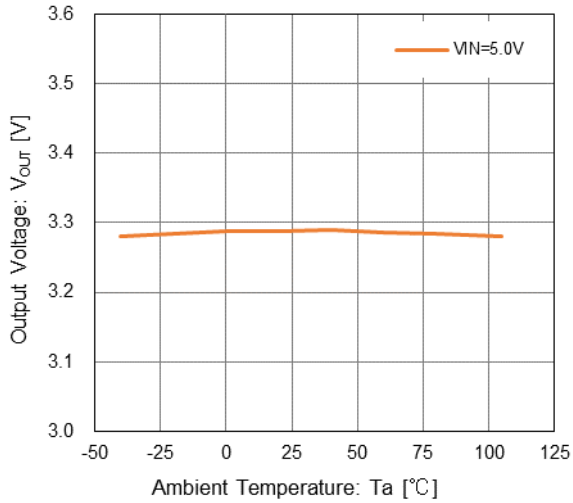
V_{OUT}=1.2V



V_{OUT}=1.8V

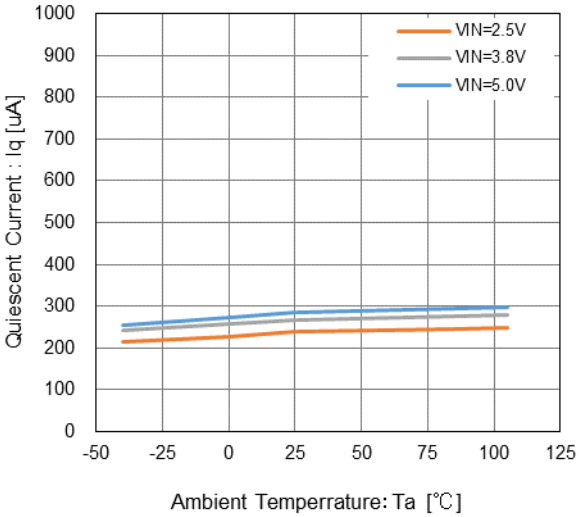


V_{OUT}=3.3V

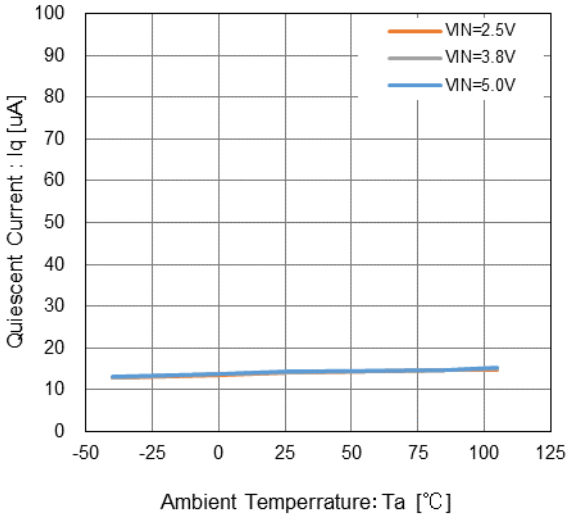


(5) Quiescent Current vs. Ambient Temperature

XCL241

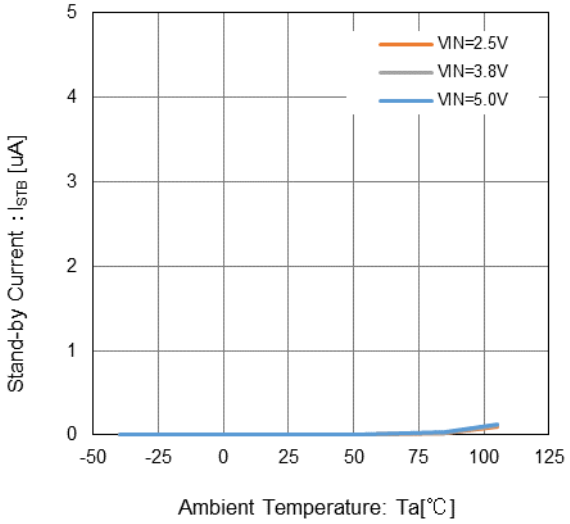


XCL242

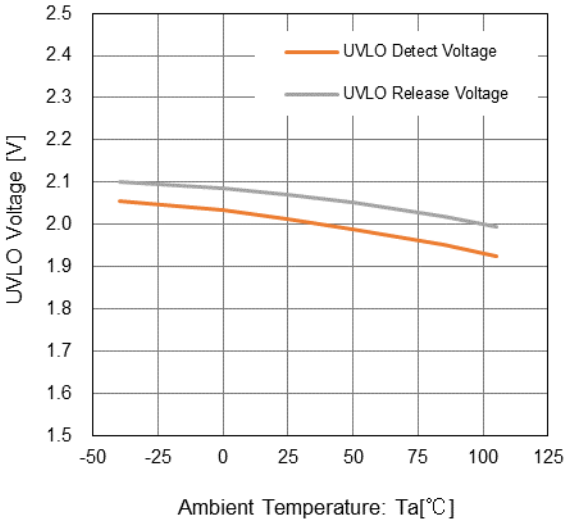


■TYPICAL PERFORMANCE CHARACTERISTICS

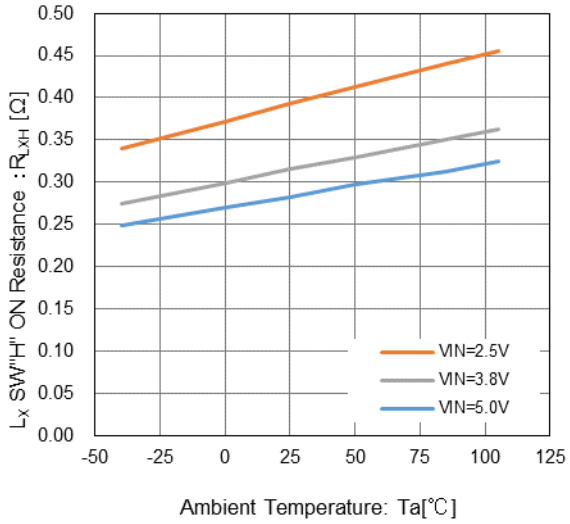
(6) Stand-by Current vs. Ambient Temperature



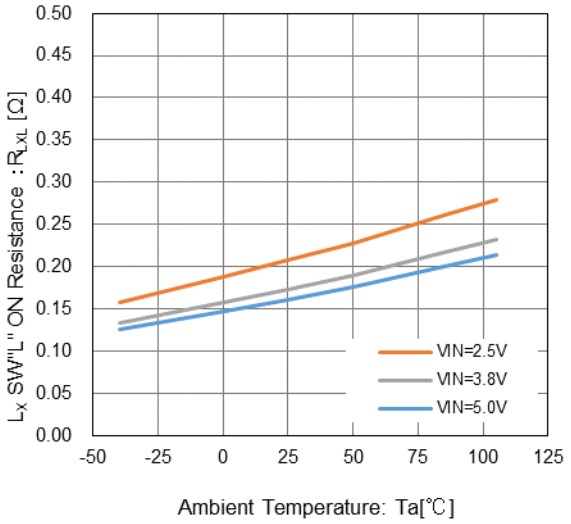
(7) UVLO Voltage vs. Ambient Temperature



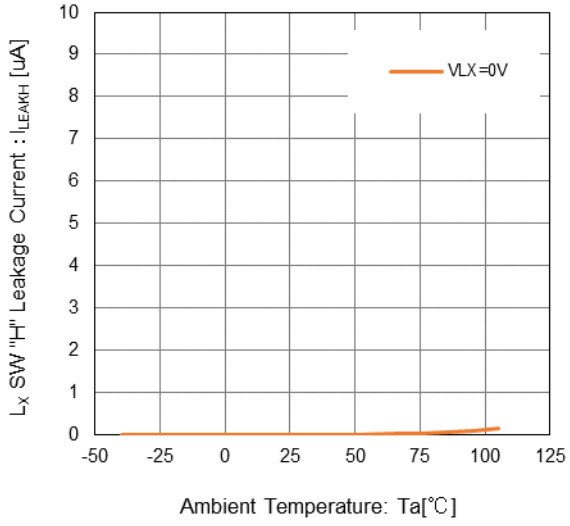
(8) Lx SW "H" ON Resistance vs. Ambient Temperature



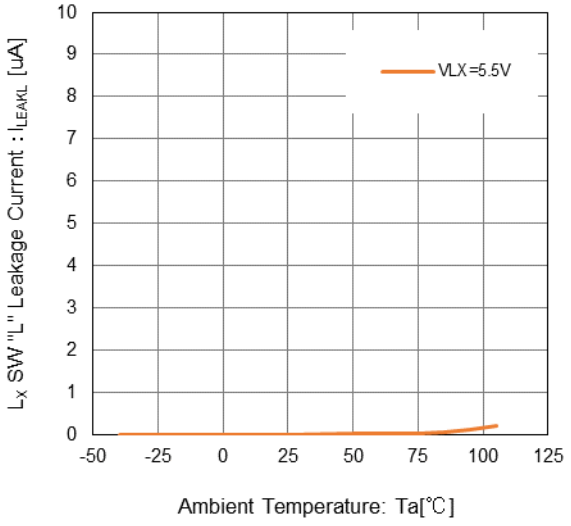
(9) Lx SW "L" ON Resistance vs. Ambient Temperature



(10) Lx SW "H" Leakage Current vs. Ambient Temperature



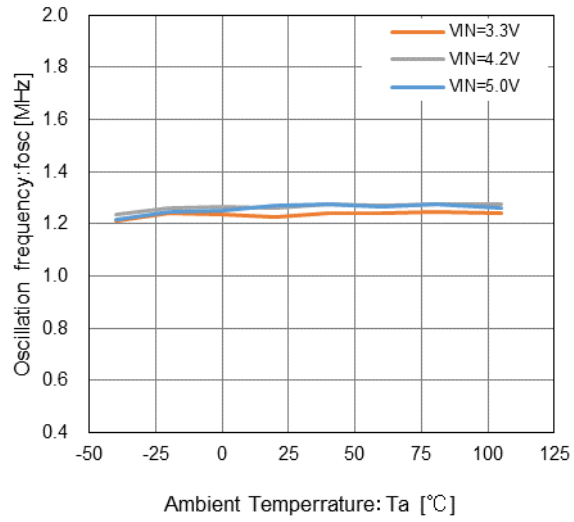
(11) Lx SW "L" Leakage Current vs. Ambient Temperature



■TYPICAL PERFORMANCE CHARACTERISTICS

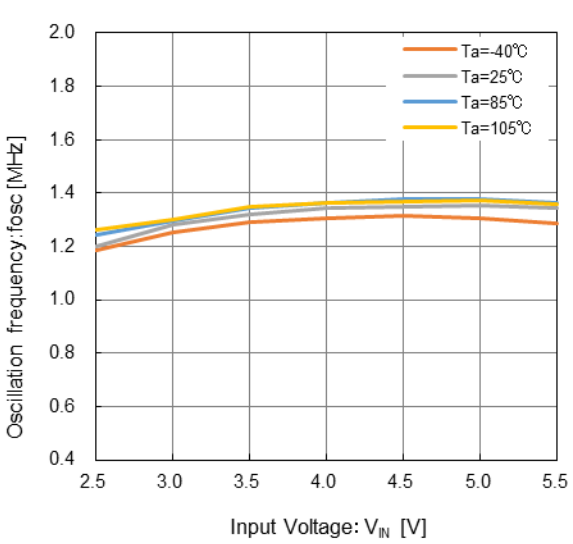
(12) Oscillation Frequency vs. Ambient Temperature

XCL241 V_{OUT}=1.8V, I_{OUT}=300mA

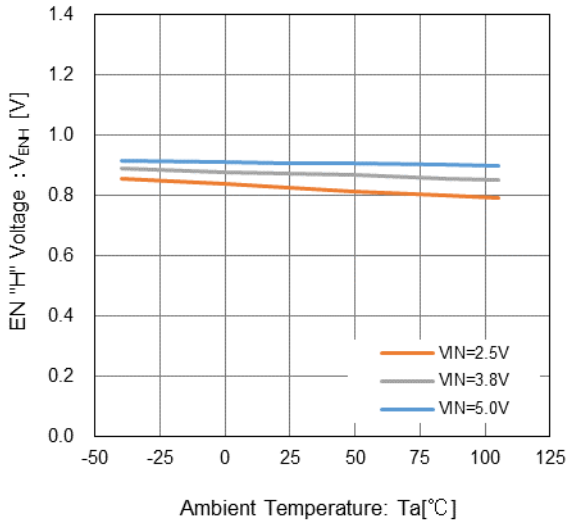


(13) Oscillation Frequency vs. Input Voltage

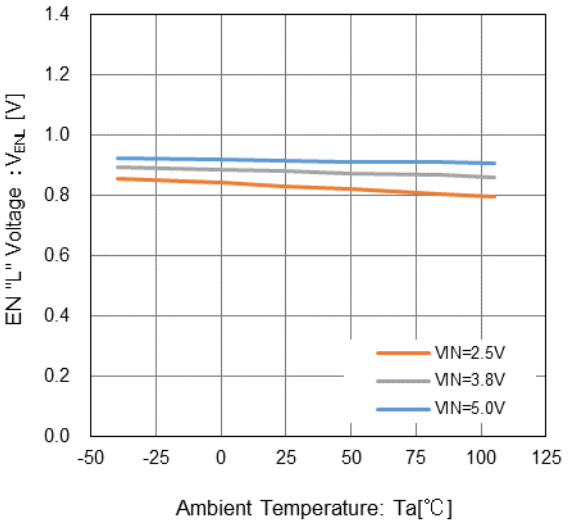
XCL241 V_{OUT}=1.8V, I_{OUT}=300mA



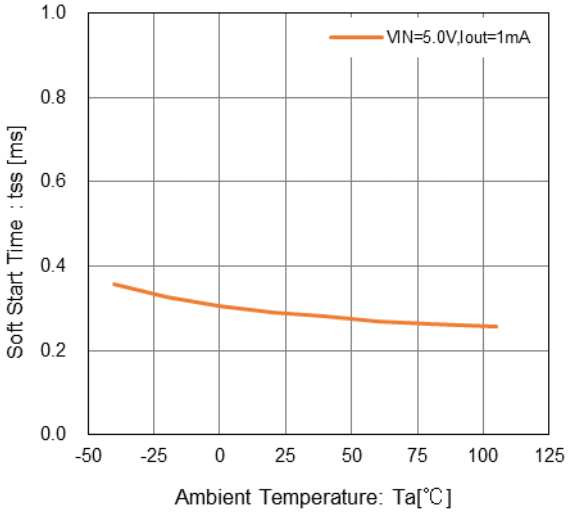
(14) EN "H" Voltage vs. Ambient Temperature



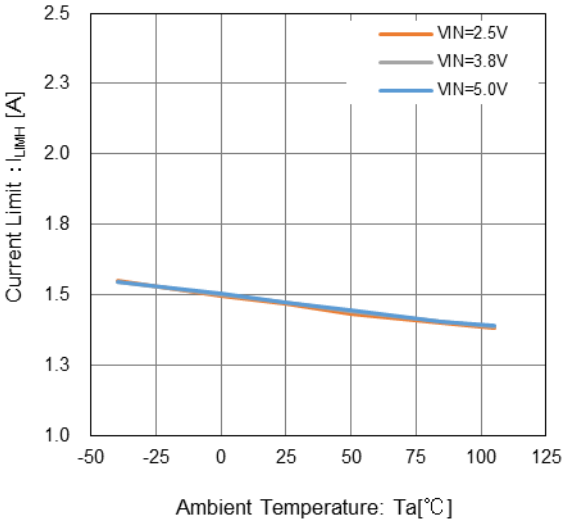
(15) EN "L" Voltage vs. Ambient Temperature



(16) Soft Start Time vs. Ambient Temperature

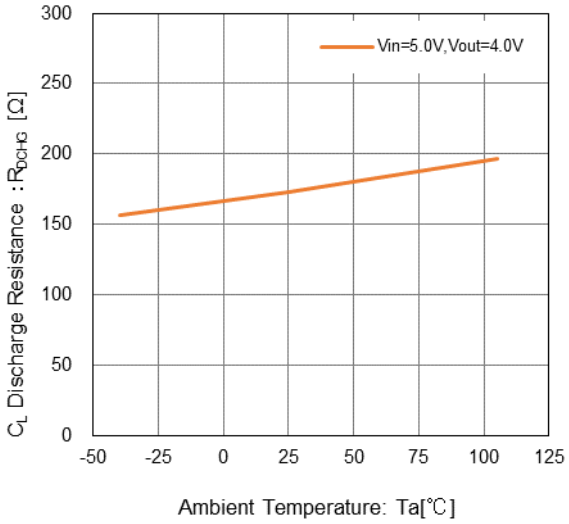


(17) Current Limit vs. Ambient Temperature

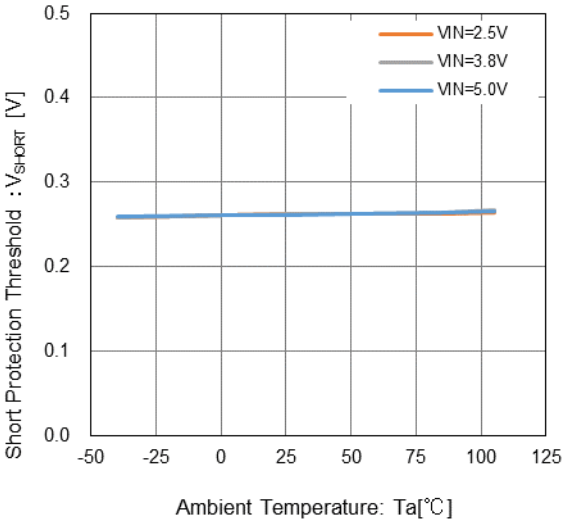


■TYPICAL PERFORMANCE CHARACTERISTICS

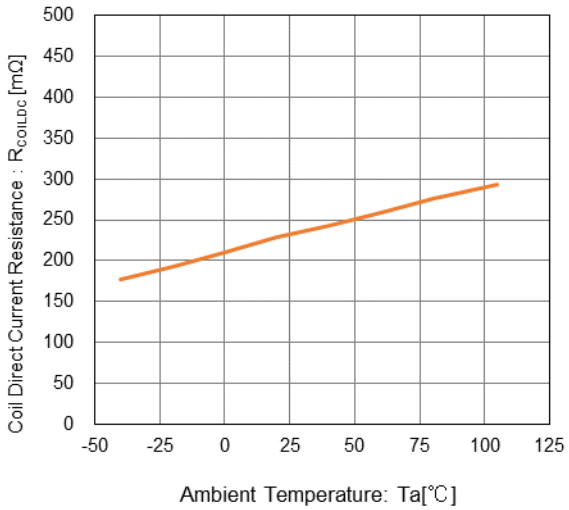
(18) C_L Discharge Resistance vs. Ambient Temperature



(19) Short Protection Threshold vs. Ambient Temperature



(20) Coil Direct Current Resistance vs. Ambient Temperature

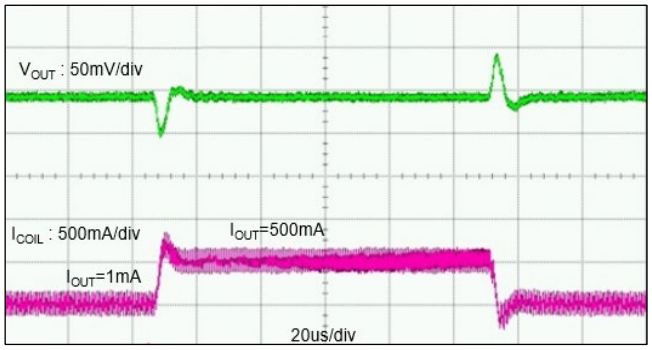


■TYPICAL PERFORMANCE CHARACTERISTICS

(21) Load Transient Response

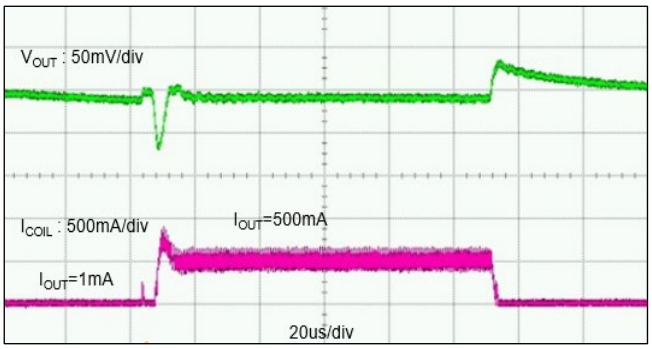
XCL241

V_{IN}=3.8V, V_{OUT}=0.8V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃



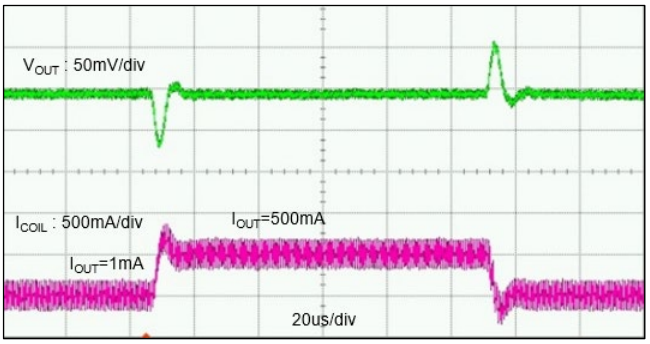
XCL242

V_{IN}=3.8V, V_{OUT}=0.8V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃



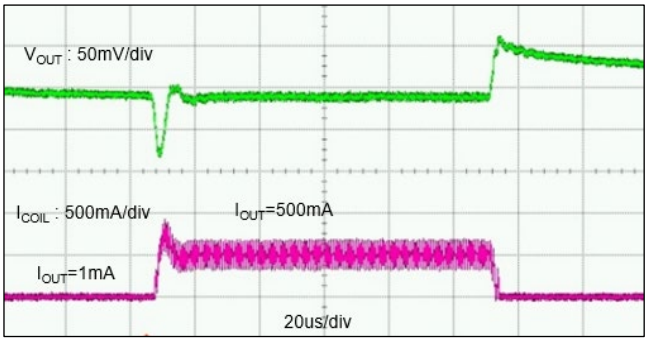
XCL241

V_{IN}=3.8V, V_{OUT}=1.8V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃



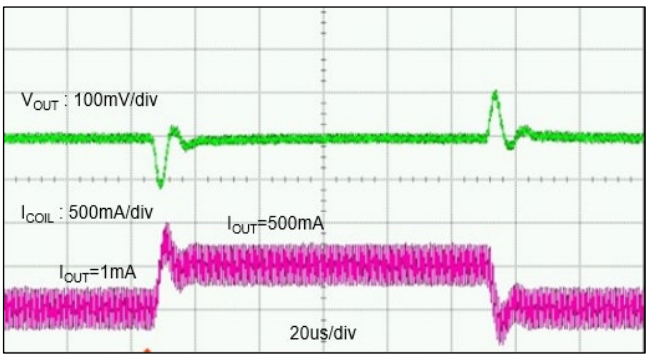
XCL242

V_{IN}=3.8V, V_{OUT}=1.8V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃



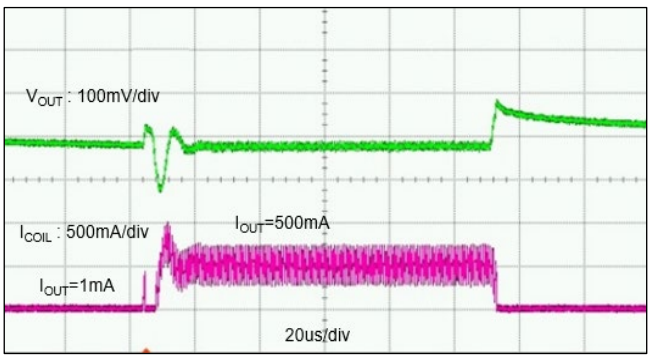
XCL241

V_{IN}=5.5V, V_{OUT}=3.6V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃



XCL242

V_{IN}=5.5V, V_{OUT}=3.6V, I_{OUT}=1mA⇔500mA(tr,tf=1us), Ta=25℃

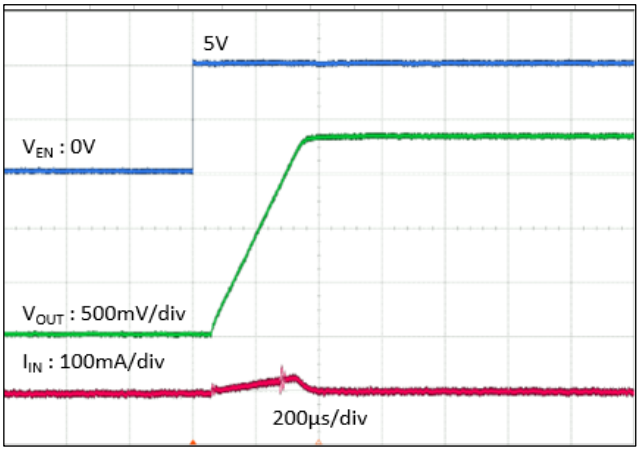


■TYPICAL PERFORMANCE CHARACTERISTICS

(22) Start-up

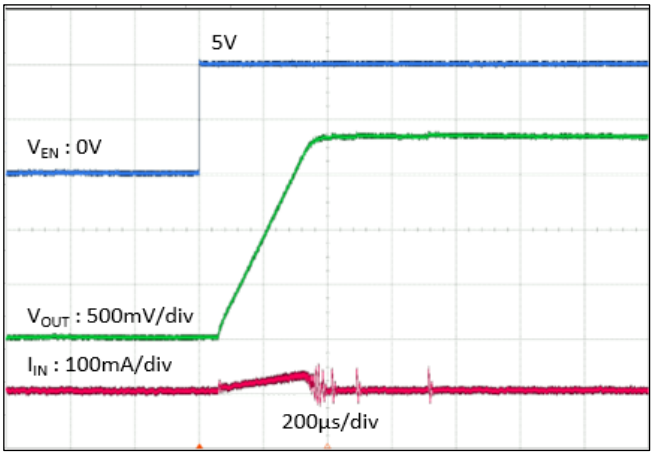
XCL241

V_{IN}=3.6V, V_{OUT}=1.8V, V_{EN}=0V⇒5V, R_L=1.8kΩ



XCL242

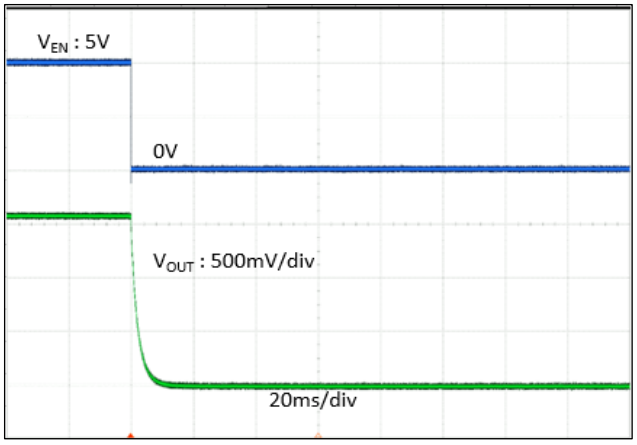
V_{IN}=3.6V, V_{OUT}=1.8V, V_{EN}=0V⇒5V, R_L=1.8kΩ



(23) Shutdown

XCL241/XCL242

V_{IN}=3.6V, V_{OUT}=1.8V, V_{EN}=5V⇒0V, R_L=1.8kΩ

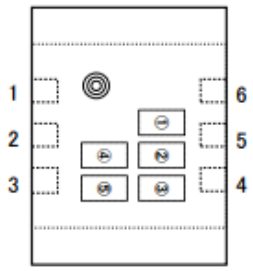


■PACKAGE INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
CL-2025-02	CL-2025-02 PKG	CL-2025-02 Power Dissipation

■MARKING RULE



① : Represents a product series.

Symbol	Product series
X	XCL241******-G
Y	XCL242******-G

② : Represents the type, the integer part of the output voltage, and the oscillation frequency.

Symbol	Type	V_{OUT}(V)	Frequency(Hz)	Product series
N	B	0.x	1.2M	XCL24*B0*1**-G
P		1.x		XCL24*B1*1**-G
R		2.x		XCL24*B2*1**-G
S		3.x		XCL24*B3*1**-G

③ : Represents the fractional part of the output voltage.

V_{OUT}(V)	Symbol	Product series
X.0	0	XCL24***0***-G
X.05	A	XCL24***A***-G
X.1	1	XCL24***1***-G
X.15	B	XCL24***B***-G
X.2	2	XCL24***2***-G
X.25	C	XCL24***C***-G
X.3	3	XCL24***3***-G
X.35	D	XCL24***D***-G
X.4	4	XCL24***4***-G
X.45	E	XCL24***E***-G
X.5	5	XCL24***5***-G
X.55	F	XCL24***F***-G
X.6	6	XCL24***6***-G
X.65	H	XCL24***H***-G
X.7	7	XCL24***7***-G
X.75	K	XCL24***K***-G
X.8	8	XCL24***8***-G
X.85	L	XCL24***L***-G
X.9	9	XCL24***9***-G
X.95	M	XCL24***M***-G

④,⑤ : Represents production lot number 01～09、0A～0Z、11～9Z、A1～A9、AA～AZ、B1～ZZ in order.
(G, I, J, O, Q, W excluded)

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